

# PHILIPS

DIRC2013

HIC  
for FAIR  
Helmholtz International Center

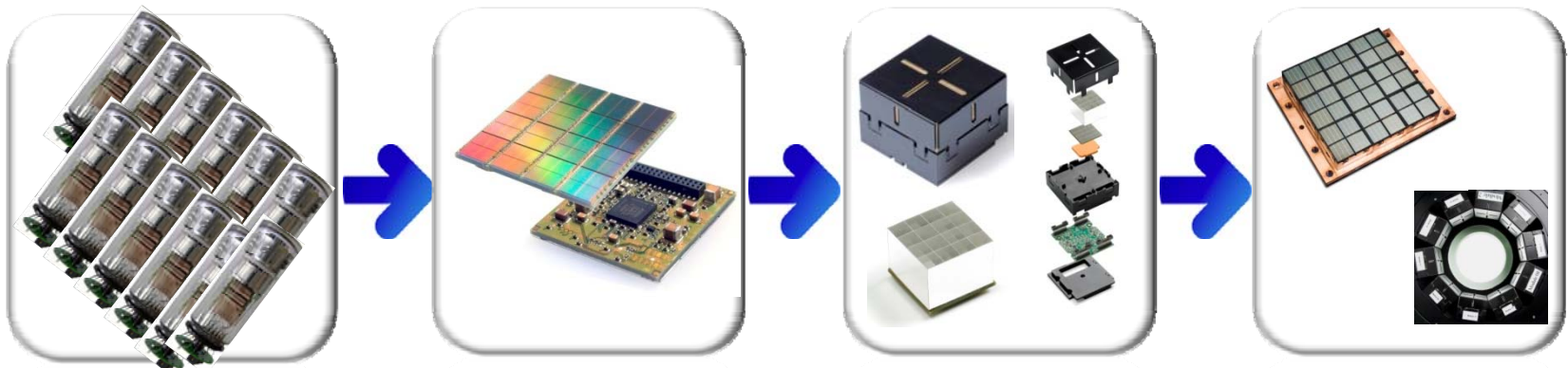
JUSTUS-LIEBIG-



UNIVERSITÄT  
GIESSEN

## Digital Photon Counting (DPC) – a scalable light detection technology with high temporal resolution

*Dr. York Haemisch, Senior Director, Philips Group Innovation  
Philips Digital Photon Counting, Aachen, Germany*



© Philips Digital Photon Counting, 2013



- **DPC represents industry trend(s)**
- **SiPM: analog vs. digital**
- **Benefits of DPC technology**
- **First POC's: PET & FARICH**
- **DPC technology concept & market approach**
- **Future Developments**



# Trends: Solid State, Digitization & Integration

**Transistor**



**Television**



**Photography**



**Telephony**

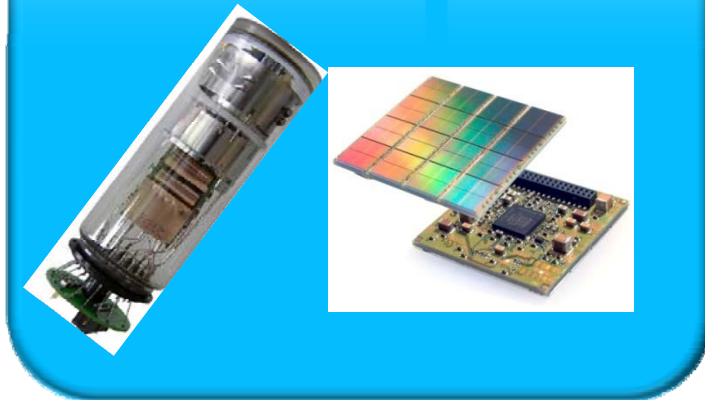


# + SOFTWARE !

**X-Ray imaging**



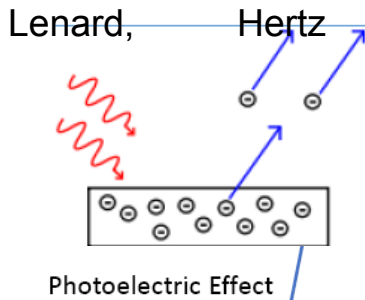
**Next?: Light Detection**



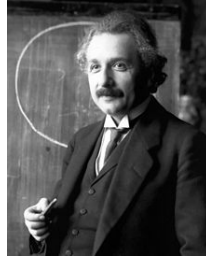
> 100 years of light detection: From **Photomultiplier Tubes (PMTs)** to **Photodiodes (PDs)**, **Avalanche Photodiodes (APDs)** to **Arrays of Geiger-Mode APDs (Silicon Photomultipliers (SiPMs))**



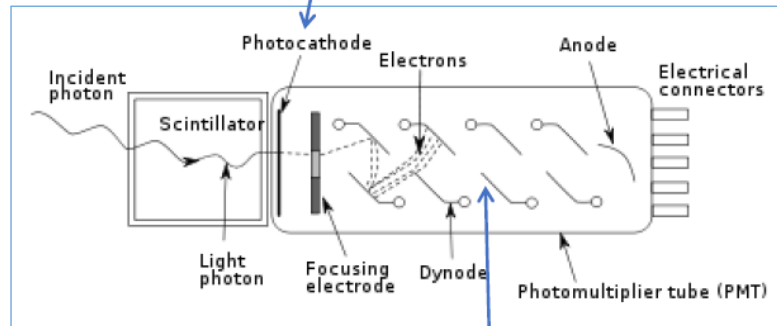
**1887**



**1905**



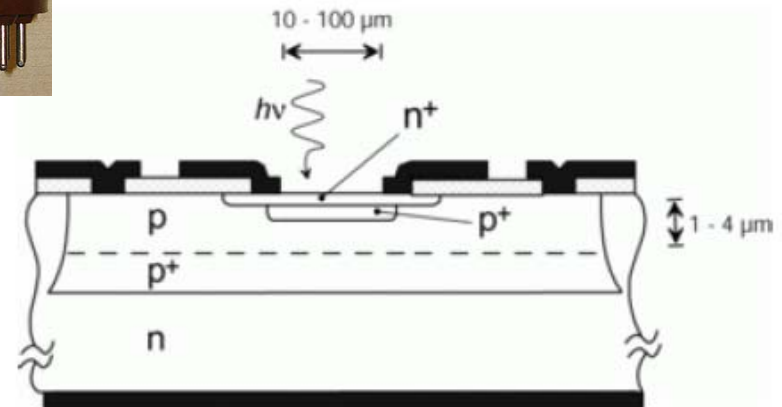
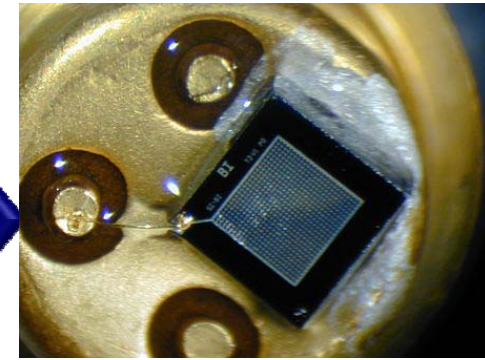
**1934**



Secondary electron emission

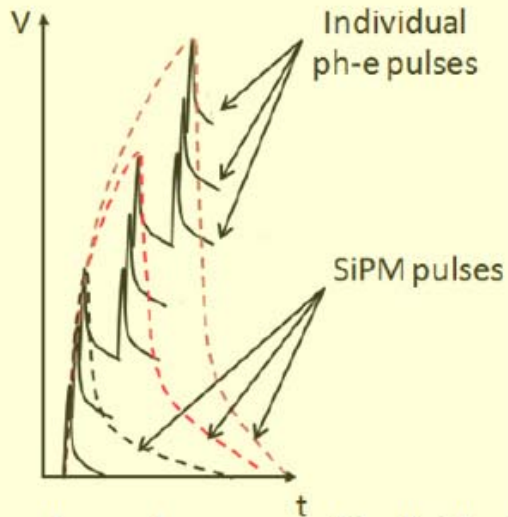
**1980's**

**Saveliev & colleagues**



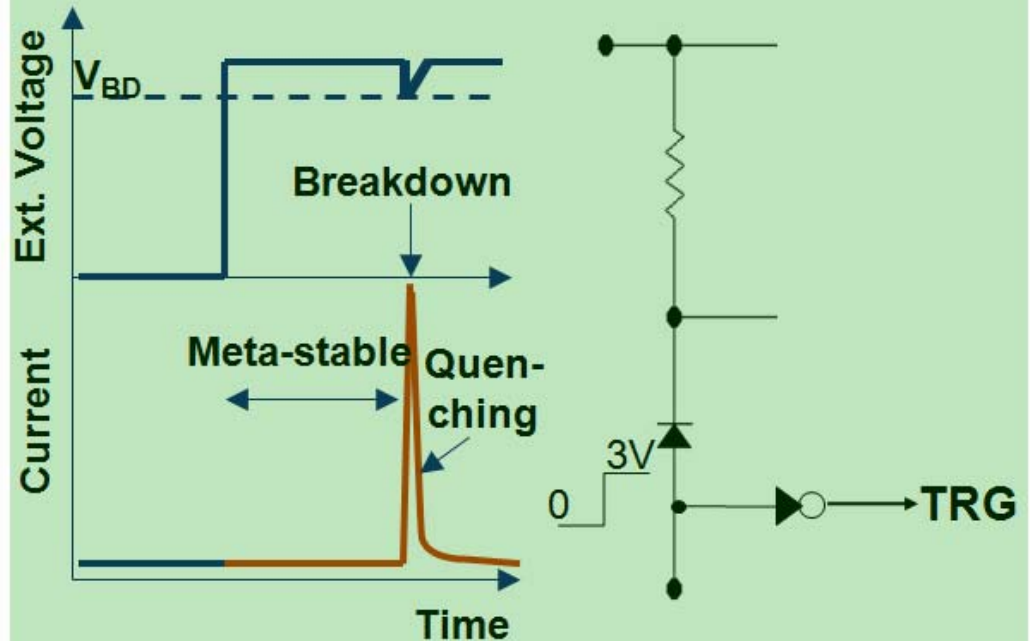
# The DPC Takes Advantage of the Binary Nature of the Geiger-Mode APD

## Analog SiPM



- Signal: analog sum of individual pulse amplitudes
- amplitudes depend on gain
- gains depend on temperature
- temperature drifts: 2-8%/K

## Digital Photon Counter (DPC)



- Signal: digital sum of trigger bins & digital time stamp from TDC
- amplitudes are not relevant
- no gain dependency, reduced temp. drift: 0.33%/K

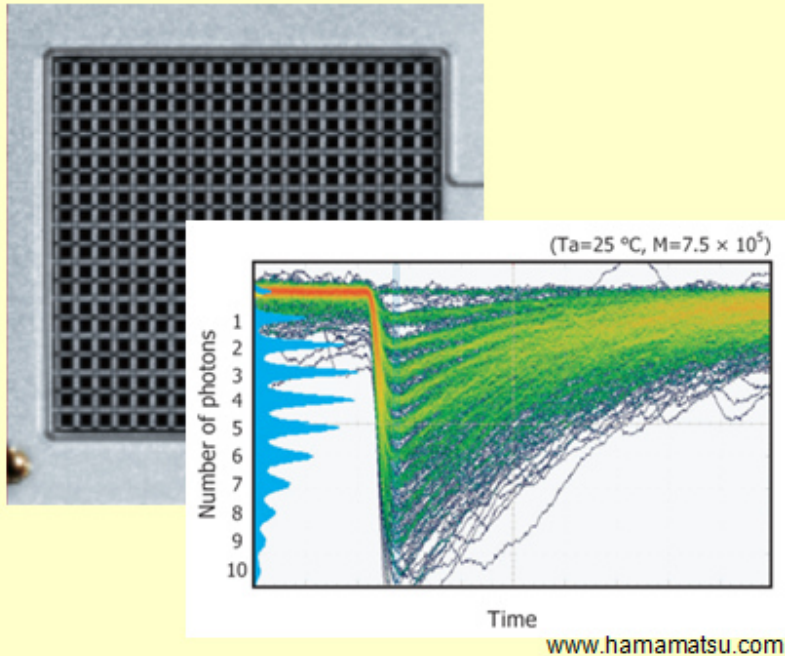
“Therefore, while the APD is a linear amplifier for the input optical signal with limited gain, the SPAD is a trigger device so **the gain concept is meaningless.**”

(source: Wikipedia)



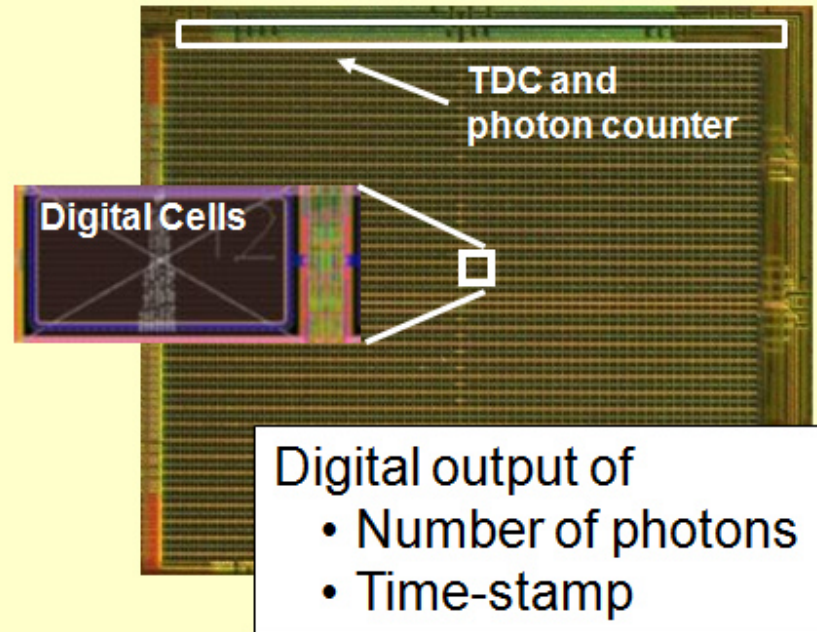
# DPC: Front-end Digitization by Integration of SPAD & CMOS Electronics

## analog SiPM



Summing all cell outputs leads to an analog output signal and limited performance

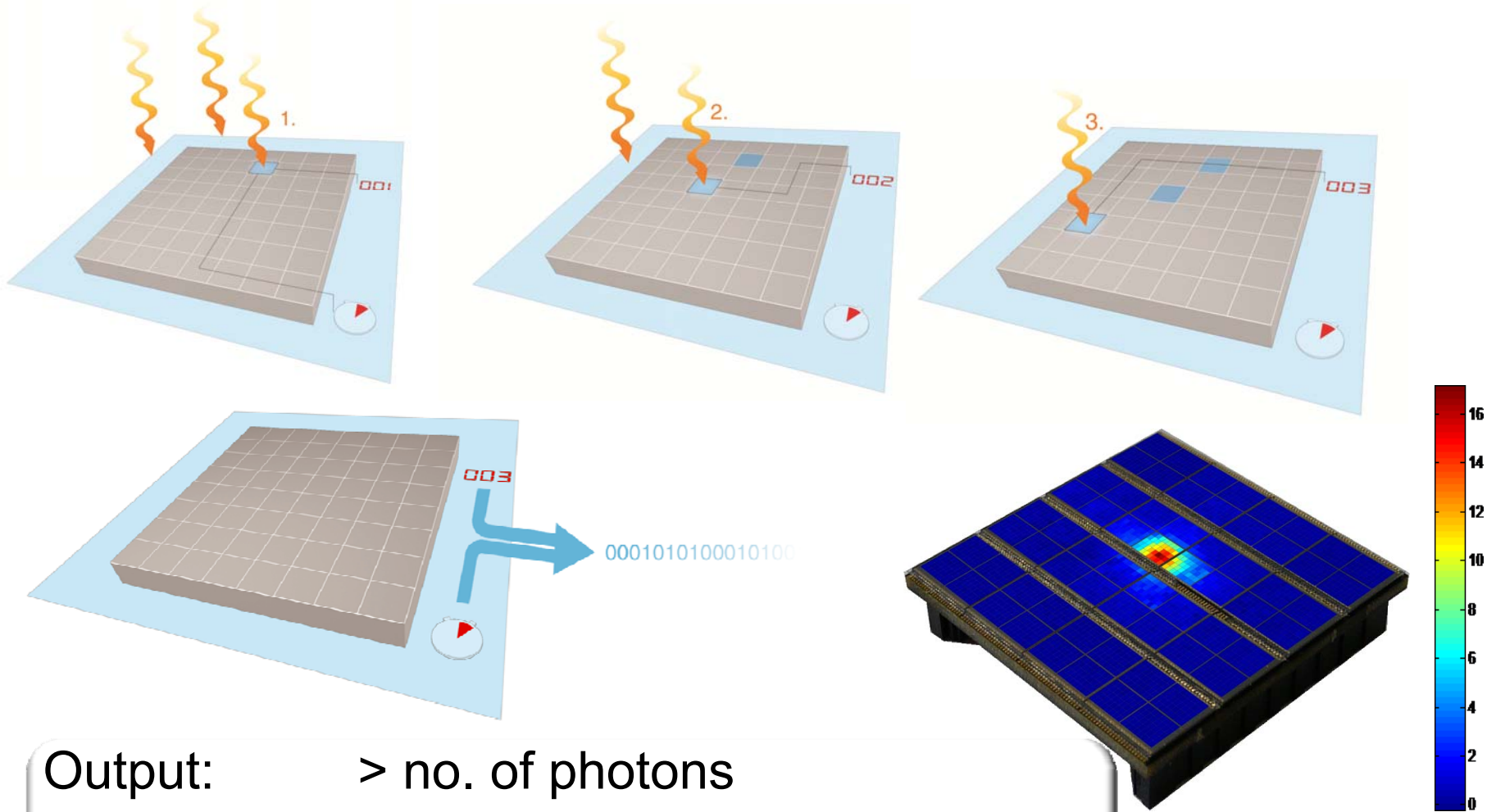
## Digital Photon Counter (DPC)



Integrated readout electronics is the key element to superior detector performance



# DPC: Now Photons are Counted Directly



Output: > no. of photons  
> time stamp(s)

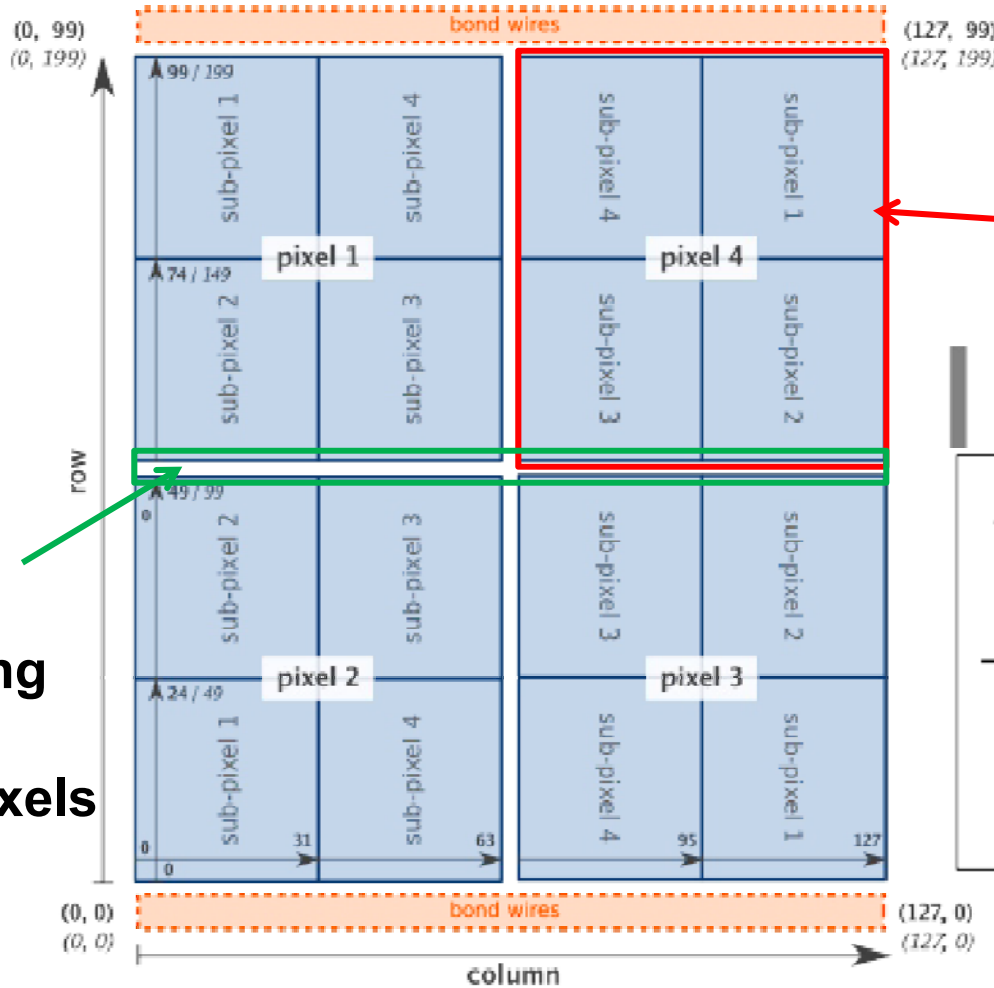
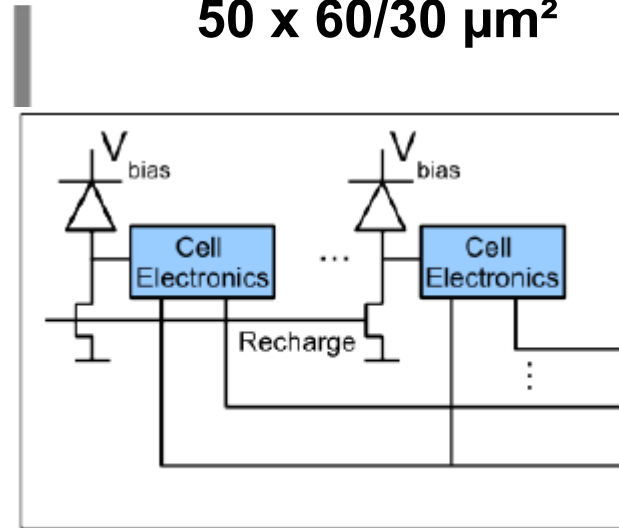
**No analog post-processing necessary!**



# DPC: Die structure



**Per Pixel:**  
**3200/6400**  
**SPAD's**  
**50 x 60/30  $\mu\text{m}^2$**

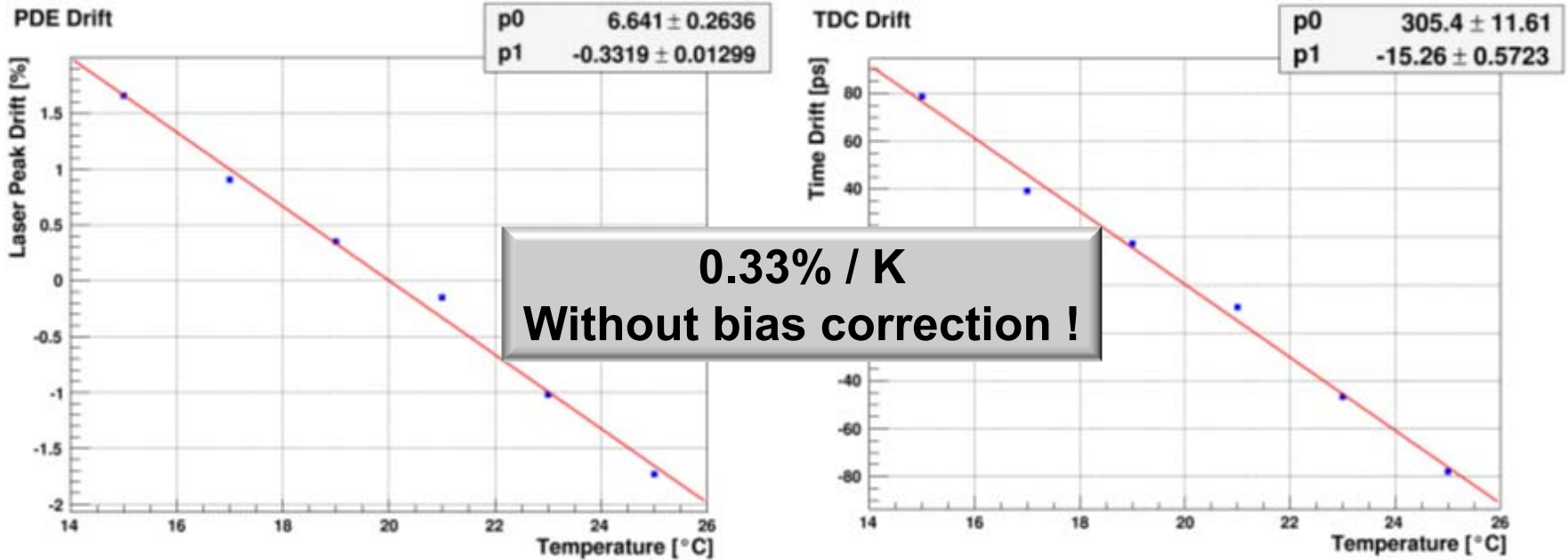


**1 Line-TDC:**  
**19.5 ps timing**  
**resolution**  
**Serving 4 pixels**





# DPC: Front End Digitization Significantly Reduces Temperature Sensitivity



- **24 ps** full-width at half-maximum timing resolution of ps-laser
- Photopeak changes **0.33%** per degree C due to changing PDE (values of analog SiPM's are ranging from 2-8%)
- Time changes **15.3 ps** per degree C (TDC + trigger network drift)

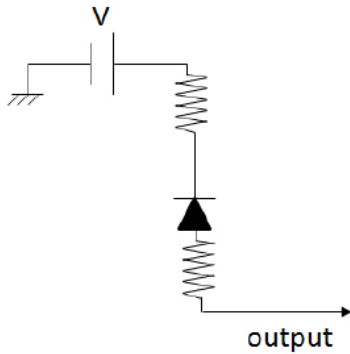


# DPC: CMOS Integration Enables Active Quenching

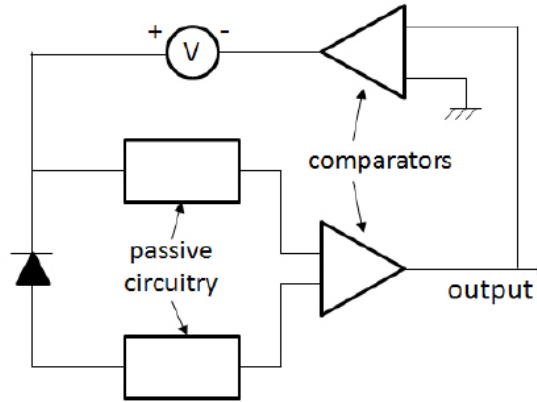
**Figure 11.** Generic schematics of a passive (left) and an active (right) quenching circuit employed at the micro-cell level (the micro-cell is represented by the diode symbol).

*Graphics from Spanoudaki & Levin, Stanford, in: Sensors (10), 2010*

Passive quenching

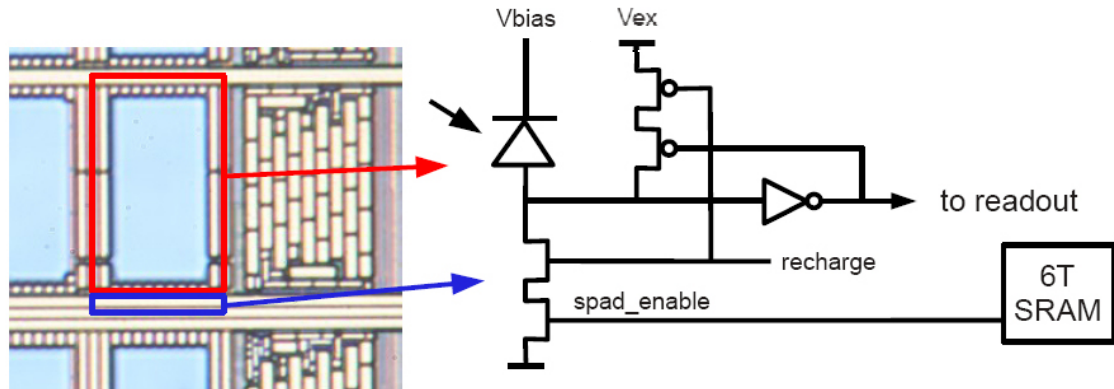


Active quenching



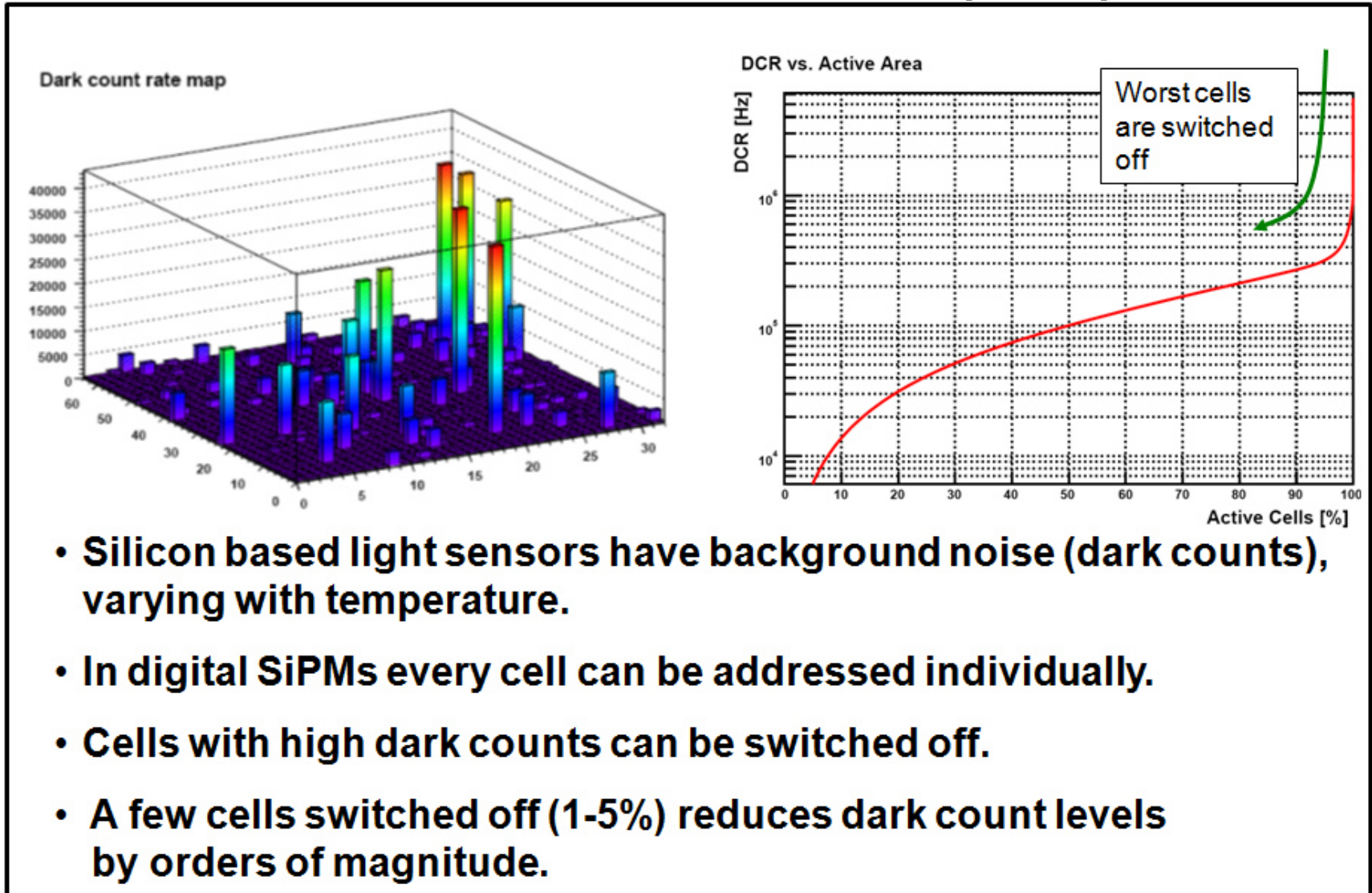
**Digital SiPMs show reduced afterpulsing (0.3%) and crosstalk.**

**Cell layout of Digital SiPM cells: Digital electronics take up only 3-6% of active area.**





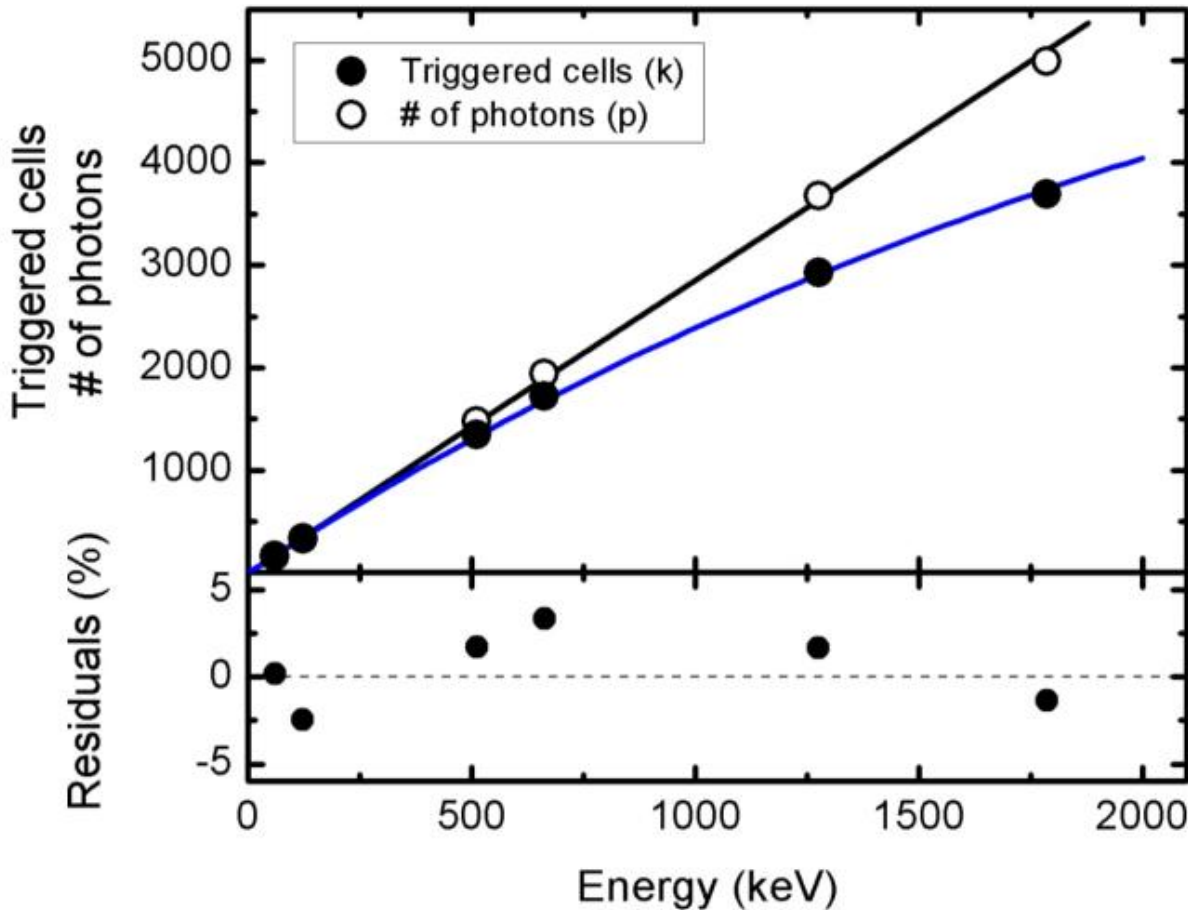
# DPC: CMOS Integration Allows Active Control of Dark Count Rate (DCR)



- Silicon based light sensors have background noise (dark counts), varying with temperature.
- In digital SiPMs every cell can be addressed individually.
- Cells with high dark counts can be switched off.
- A few cells switched off (1-5%) reduces dark count levels by orders of magnitude.



# DPC: Enables Easy Linearity Correction



$$p = -N \cdot \ln\left(1 - \frac{k}{N}\right)$$

N: active cells (6400)

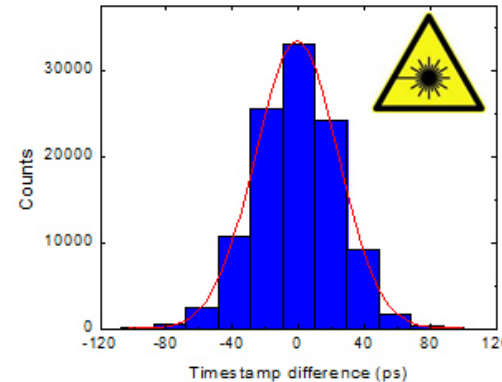
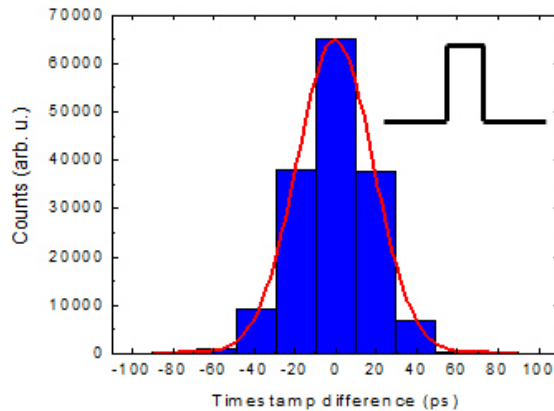
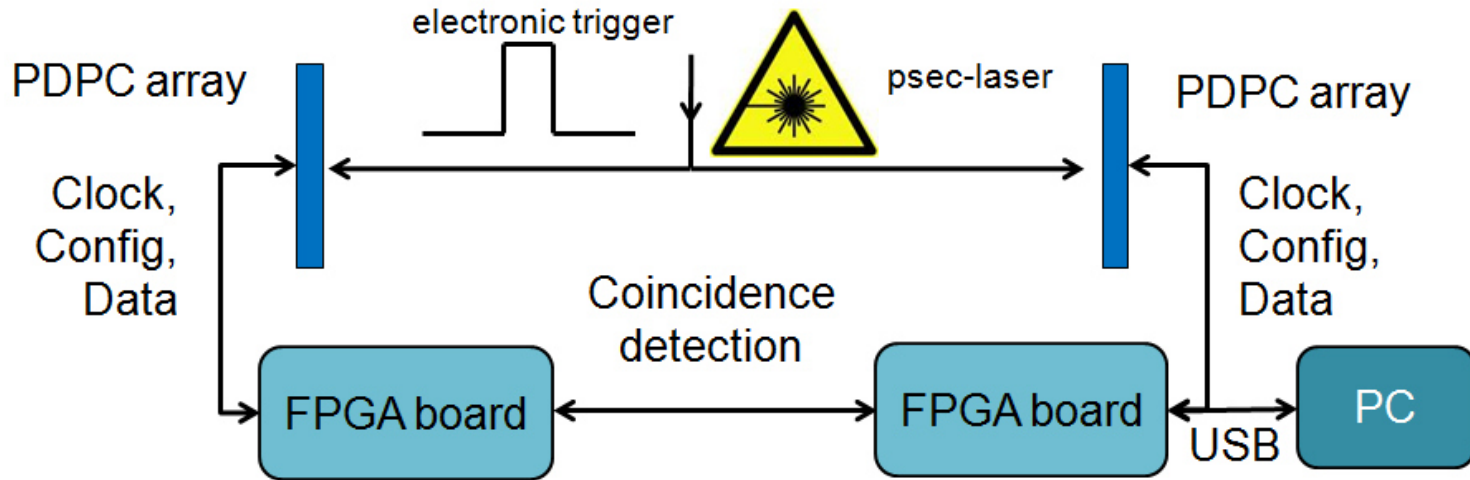
k: triggered cells

p: # of photons

- Experiments taken at room temperature
- No temperature stabilization
- **Correction more difficult with analog SiPMs**



# DPC: Integration of TDC on Chip Provides Superior Timing Across Whole Arrays



Contribution of: **TDC network**

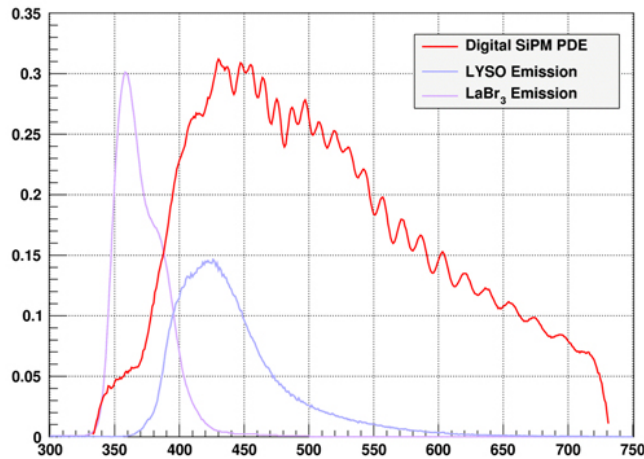
Contribution of: **TDC network + diodes**



# DPC: Higher PDE than PMT is Possible

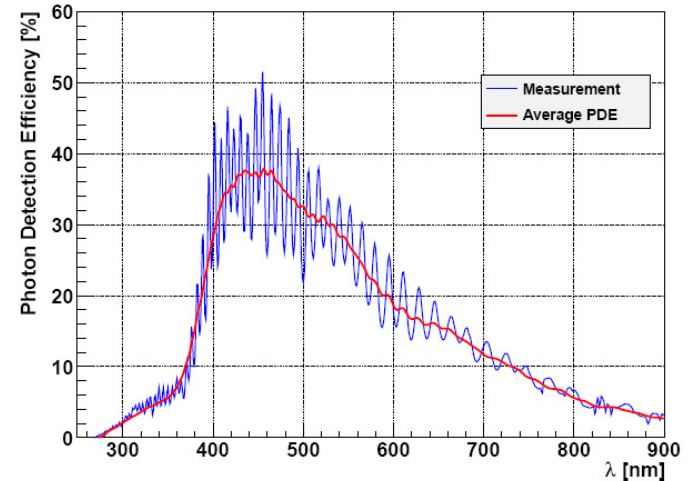
## DPC6400-22-44

Photon Detection Efficiency



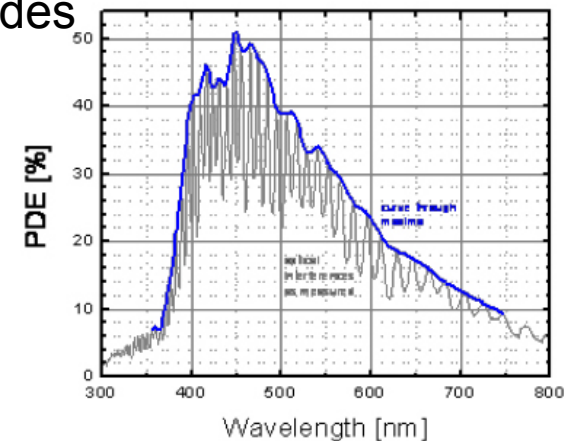
## DPC3200-22-44

Photon Detection Efficiency



- 3.3V excess voltage, -20°C, randomly selected diodes
- Measured one diode at a time, 50 cm slit
- Parallel measurement with PIN photodiode
- Transmission window not optimized yet → strong decline towards dark blue/UV
- no ARC → strong interference patterns

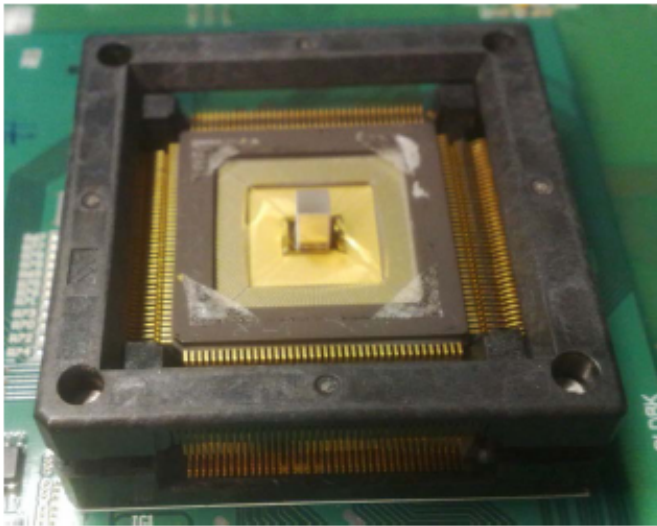
DLS3200-22



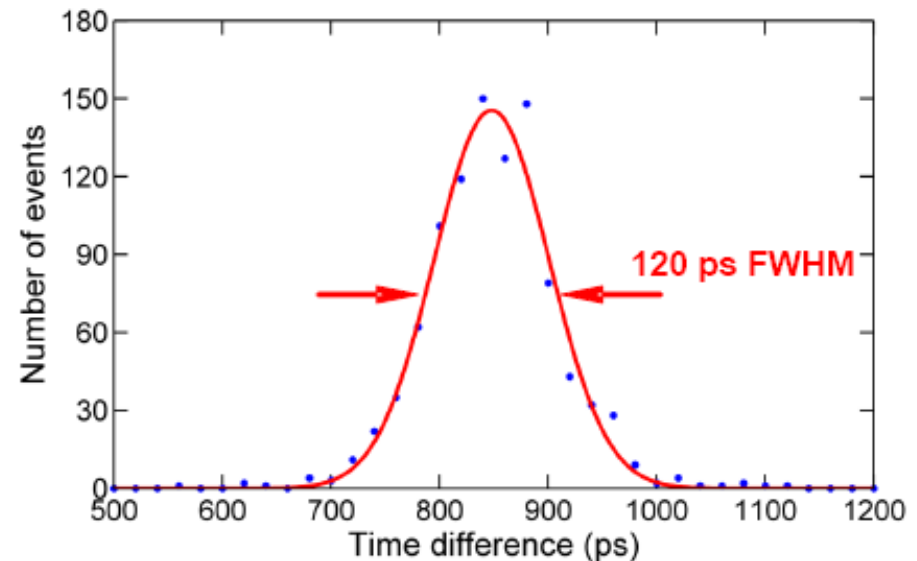


# DPC: Timing Resolution with Single Short LSO:Ca Crystal

3 mm x 3 mm x 5 mm Ca co-doped LSO:Ce on PDPC demonstrator chip



Photograph of Ca co-doped LSO:Ce crystal mounted on dSiPM demonstrator chip

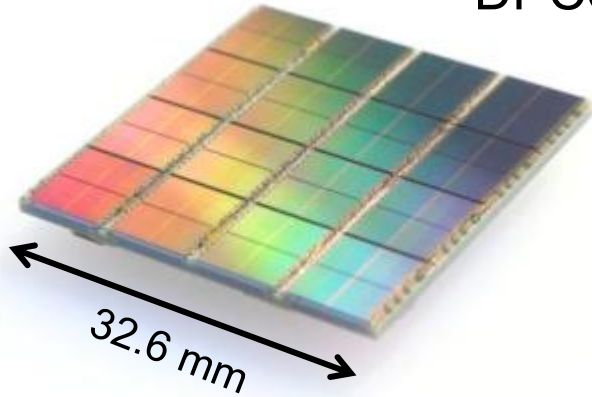


- Time difference spectrum measured with a Na-22 point source
- CRT = 120 ps FWHM (for two detectors in coincidence) at room temperature



# DPC is an Integrated “Intelligent” Sensor

DPC3200-22-44  
DPC6400-22-44

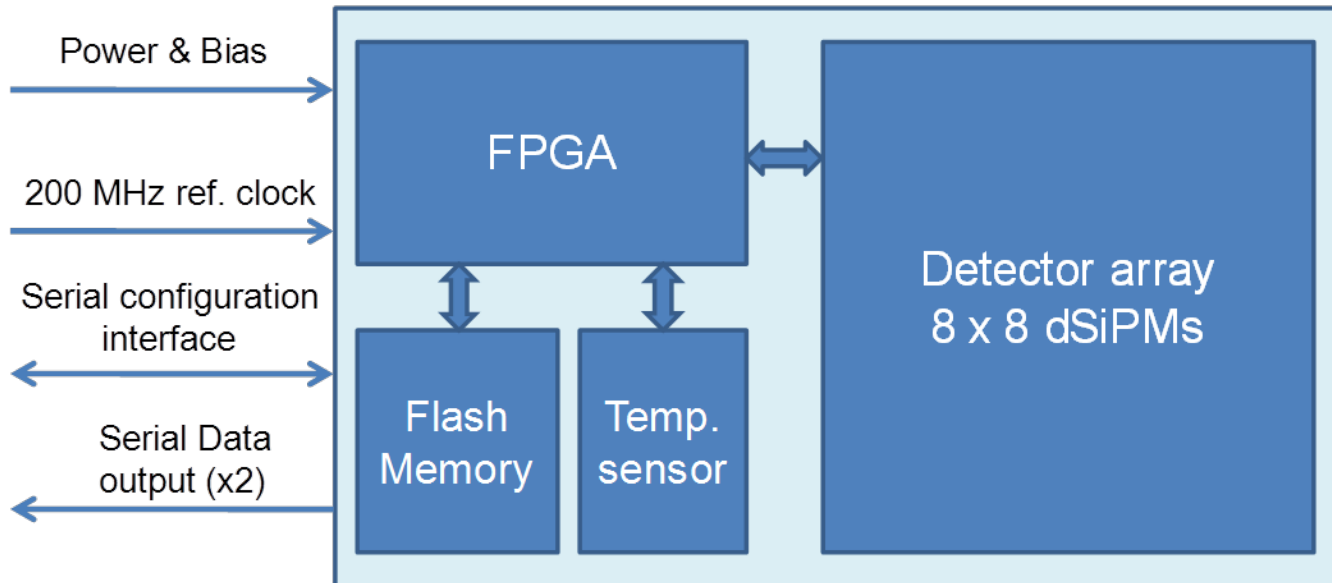


## FPGA

- Clock distribution
- Data collection/concentration
- TDC linearization
- Saturation correction
- Skew correction

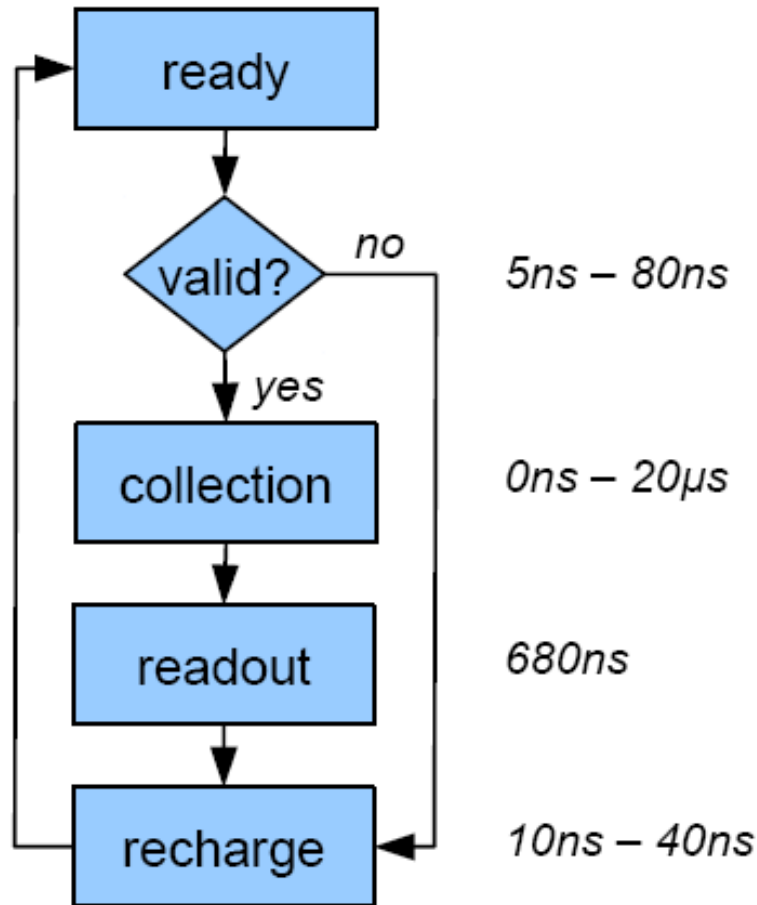
## Flash

- FPGA firmware
- Configuration
- Inhibit memory maps





## *DPC: Typical Acquisition Sequence (example)*



- 200MHz (5ns) system clock
- Variable light collection time up to 20µs
- 20ns min. dark count recovery
- dark counts => sensor dead-time
- data output parallel to the acquisition of the next event (no dead time)
- Trigger at 1, ≥2, ≥3 and ≥4 photons
- Validate at ≥4 ... ≥64 photons (possible to bypass event validation completely)

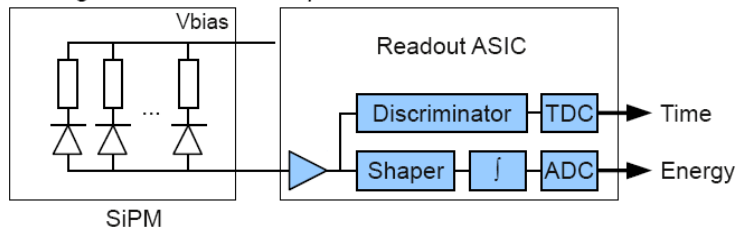


# DPC is an Integrated, Scalable Solution

## Analog SiPM

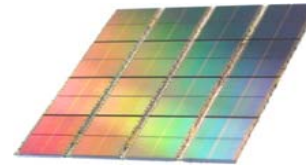


Analog Silicon Photomultiplier Detector

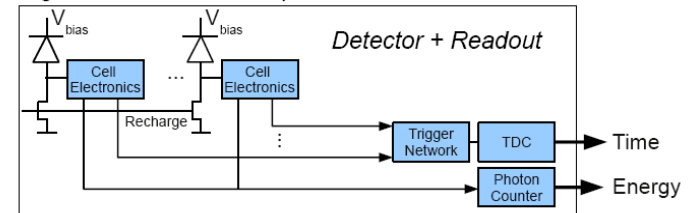


- discrete, limited integration
- analog signals to be digitized
- dedicated ASIC needed
- difficult to scale

## Digital SiPM



Digital Silicon Photomultiplier Detector

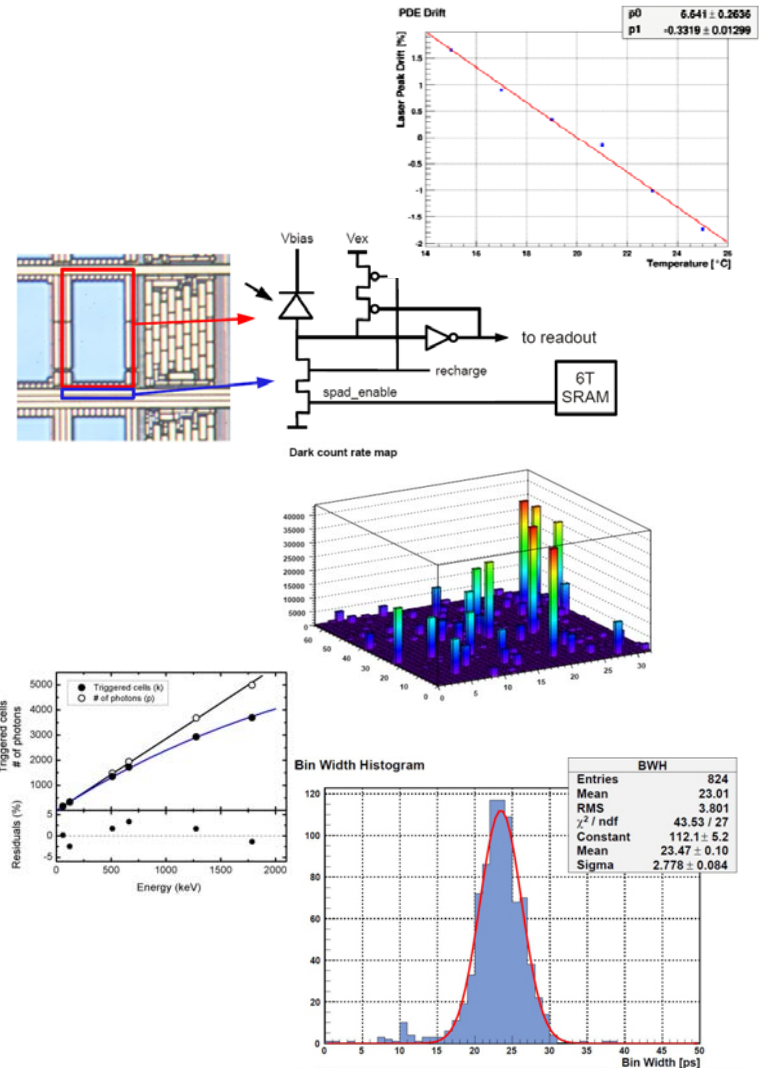


- fully integrated
- fully digital signals
- no ASIC needed
- fully scalable



# Sub-Summary: Advantages of Philips' DPCs

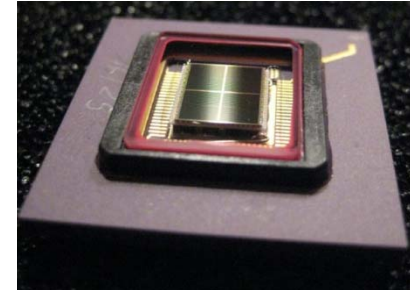
- significantly reduced temperature sensitivity ( $\sim 10^{-1}$ )
- active quenching reduces afterpulsing & crosstalk ( $\sim 10^{-1}$ )
- individually addressable cells enable DC control ( $\sim 10^{-2}$ )
- better linearity (& correction)
- better intrinsic timing resolution due to integrated TDCs ( $\sim$  factor 5)
- no analog electronics, no ADCs, no ASICs





**DPC technology is SCALABLE**

**2 x 2 pixels in ceramic package with Peltier Cooling**



**8 x 8 pixels in frames**



**Coolable Detector Modules (256 pixels)**

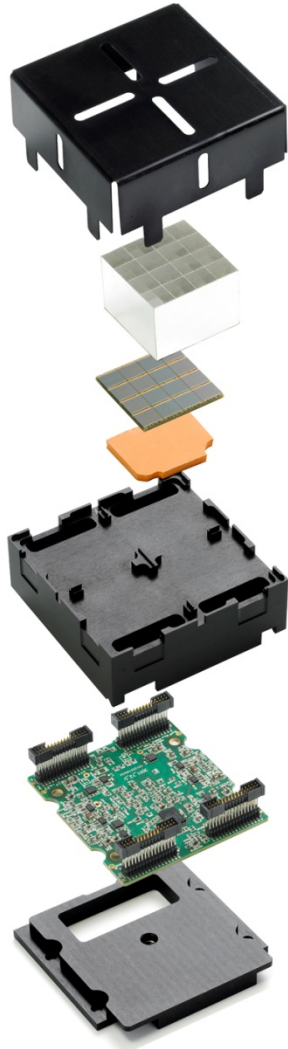


**Coolable Detector Rings/Areas (any number of pixels)**





## Philips DPC Technology: Detector Modules

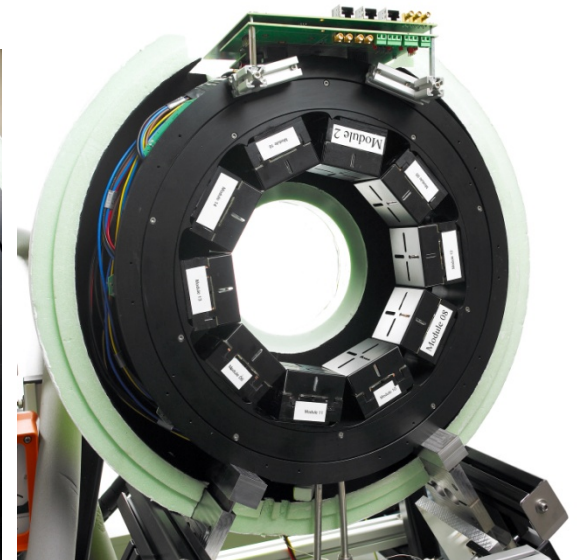


- **4 DPC sensor arrays (tiles)**
- **~ 6.6 x 6.6 cm<sup>2</sup>**
- **usable with or w/o scintillator crystals**
- **variable scintillator geometries**
- **Module board with FPGA, pre-processing capability & simple interface**
- **experimentally cooled to - 40°C**

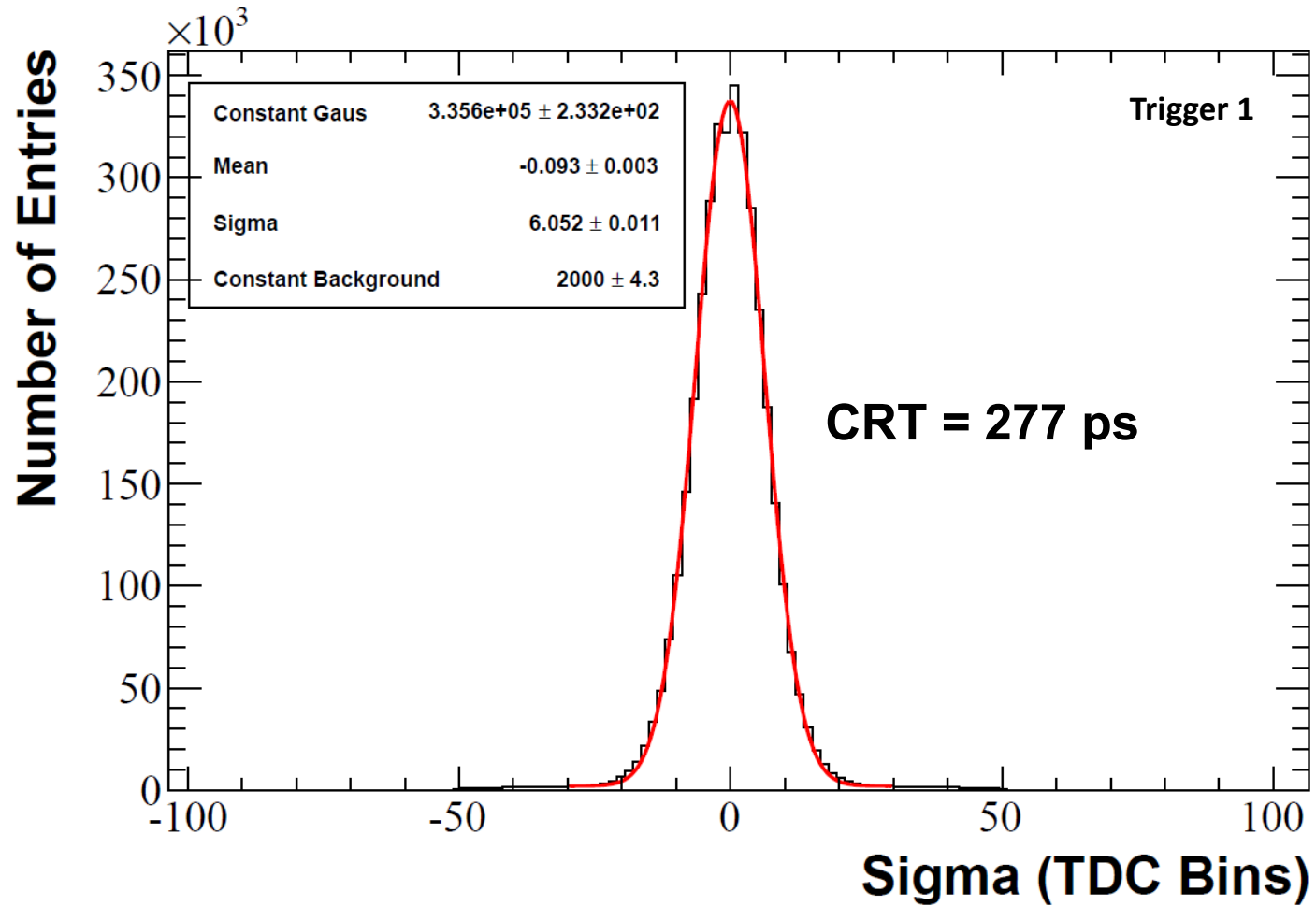


# PDPC Technology: Test PET-Ring (@FZ Juelich)

- Inner Diameter (face-to-face): 20 cm
- 10 modules a 4 sensors
- LYSO 4 x 4 x 22 mm<sup>2</sup>
- Coolable down to 0°C
- Sensor temp. : ~ 5-10°C



# Timing Coincidence Resolution



**0x00 validation setting**

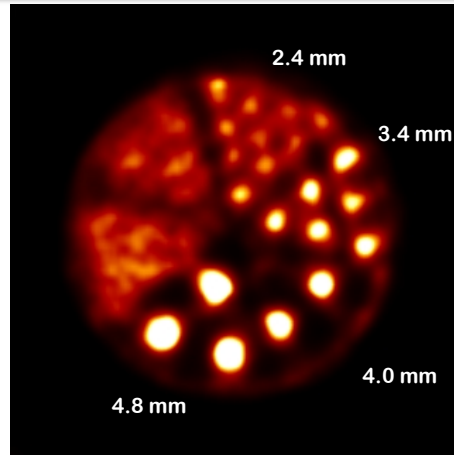
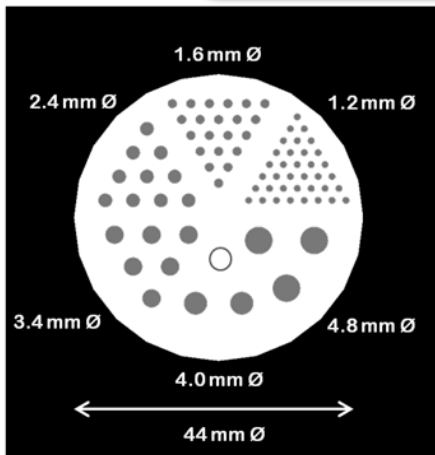
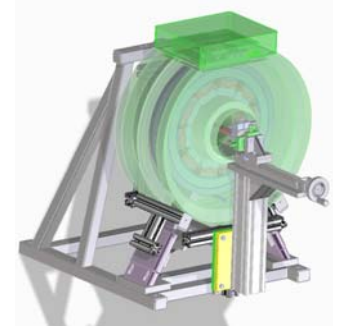
**CRT (Trigger 1, CPI array) ~277 ps**

**CRT (Trigger 2, CPI array) ~362 ps**

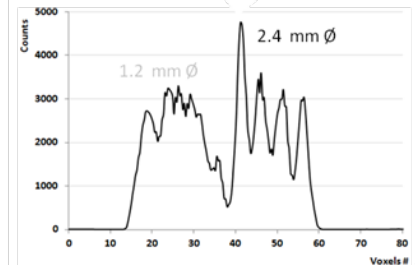
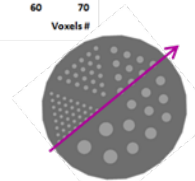
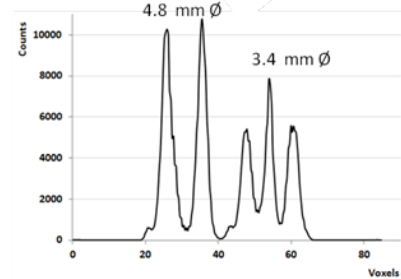
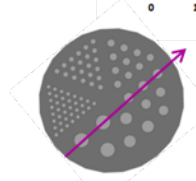
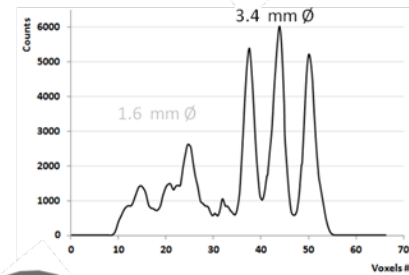
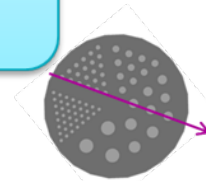
# Image Quality Overview



- Fillable rods (44 mm diam. / 34 mm length)
- 90 min acquisition (25 MBq of 18F)
- Trigger 2 at 7-9°C (internal tile temperature)
- Energy (ER 13% & clustering) and time (TR 390 ps) calibrations applied
- Energy window of [440;660] keV and time window of 3 ns [-1.5;1.5]



*PURE/OSEM (0.5 mm voxels), no norm., no decay time, all corrections applied.  
15.2% randoms, 5.0% scatters*

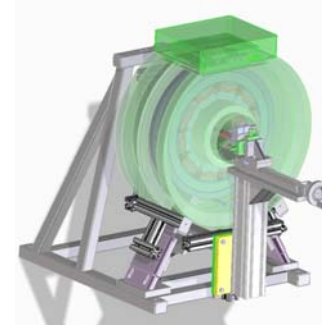




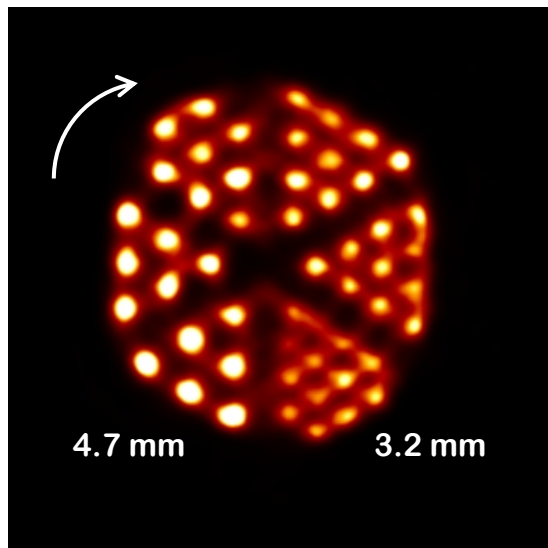
# Image Quality Overview



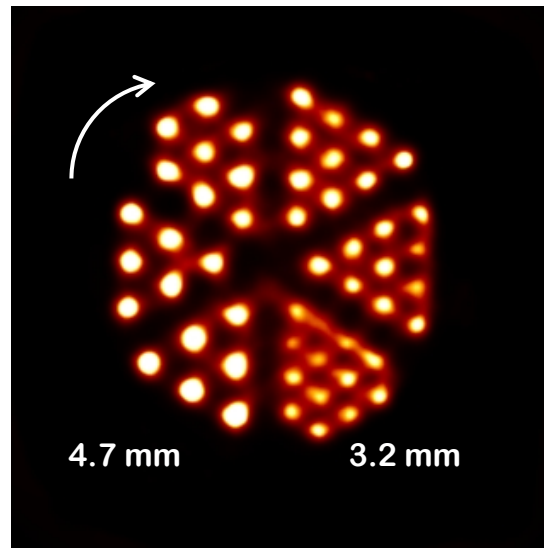
- Hot rod phantom (**70 mm diameter**)
- 1h data acquisition (10-15 MBq  $^{18}\text{F}$ )
- Trigger 2 at 7-9°C (internal tile temperature)
- Energy (RE 13% & clustering) and time (TR 390 ps) calibrations applied
- Energy window of [440;660] keV and time window of 3 ns [-1.5;1.5]



**Without TOF**



**With TOF (266 ps)**



*PURE/OSEM (0.5 mm voxels), no norm., no decay time, all other corrections applied.*

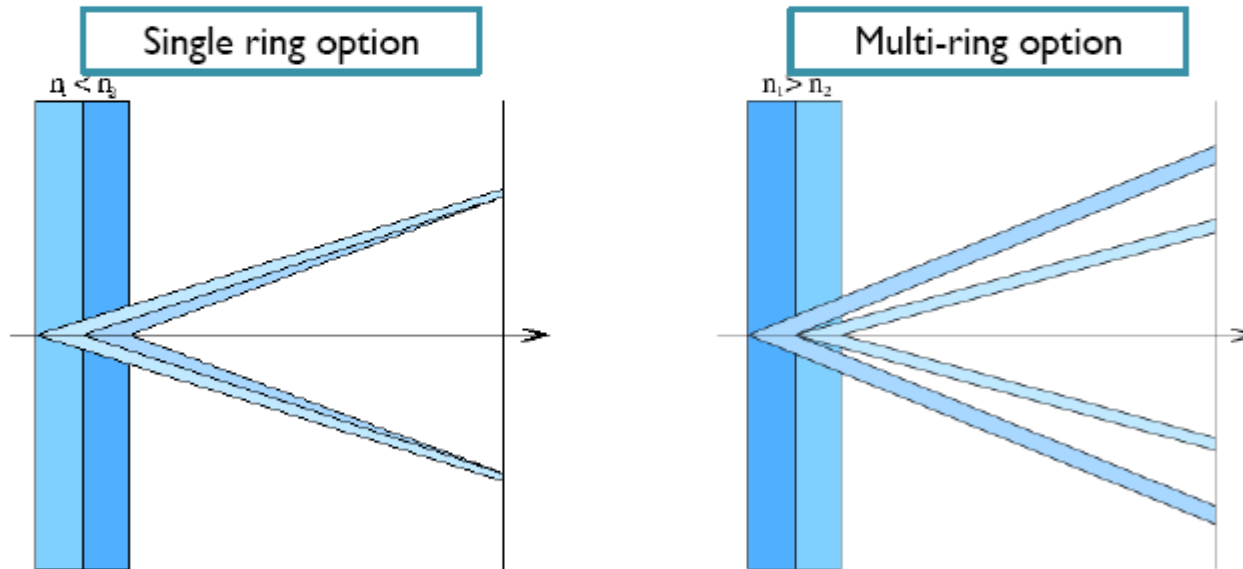


# DPC in High Energy Physics: FARICH Detector

## FARICH concept

### Focusing Aerogel RICH – FARICH

Improves proximity focusing design by reducing radiator thickness contribution into the Cherenkov angle resolution



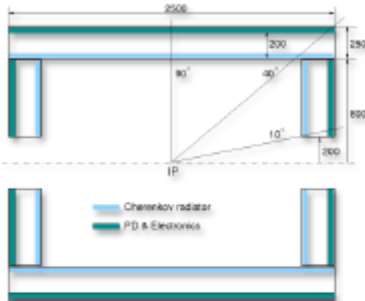
T.Iijima et al., NIM A548 (2005) 383  
 A.Yu.Barnyakov et al., NIM A553 (2005) 70

13/02/2013 VCI 2013



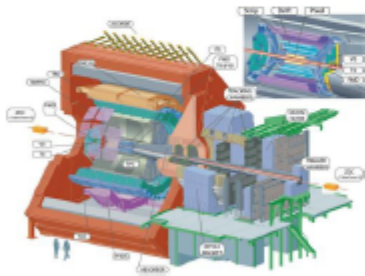
# DPC in High Energy Physics: FARICH Detector

## FARICH projects and proposals



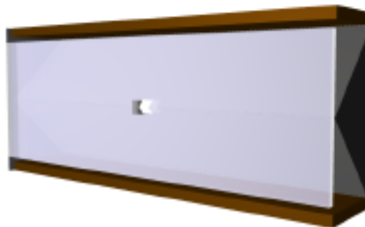
**FARICH for Super Charm-Tau Factory (Novosibirsk)**

Particle ID:  $\mu/\pi$  up to 1.7 GeV/c  
 21m<sup>2</sup> detector area (SiPMs)  
 ~1M channels



**FARICH for ALICE HMPID upgrade**

Particle ID:  $\pi/K$  up to 10 GeV/c, K/p up to 15 GeV/c  
 3m<sup>2</sup> detector area (SiPMs)



**Forward Spectrometer RICH for PANDA**

Particle ID:  $\pi/K/p$  up to 10 GeV/c  
 3m<sup>2</sup> detector area (MaPMTs or SiPMs)



# First test of DPC in High Energy Physics: FARICH Detector @ CERN, June 2012

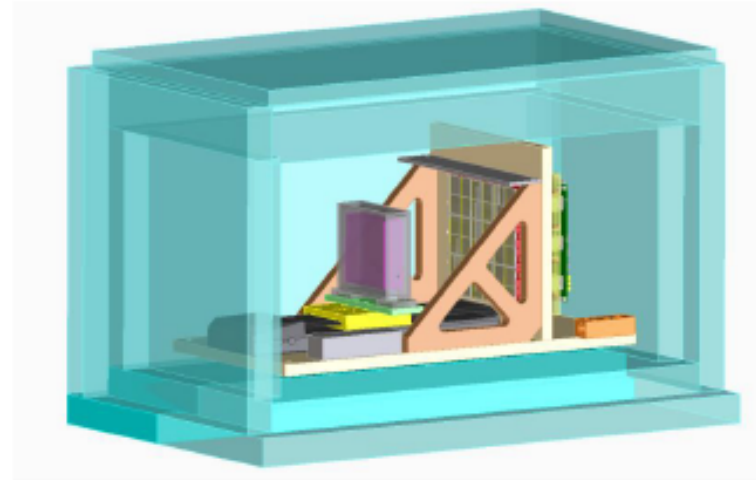
## Main objective:

Proof of concept: full Cherenkov ring detection with DPC array

## Timeline:

- Started to envisage:  
**28/02/12**
- Requirements for the FARICH prototype test setup fixed: **30/04/12**
- Prototype operational @ Aachen Labs: **03/06/12**
- Installed @ CERN: **12/06/12**
- Subsequent beam runs for 12 days until **25/06/12** with smooth setup operation

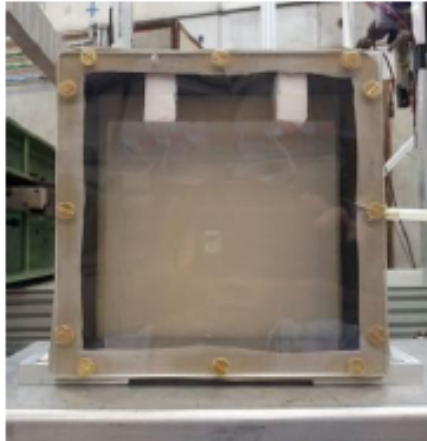
*Fast prototyping!*



13/02/2013 VCI 2013

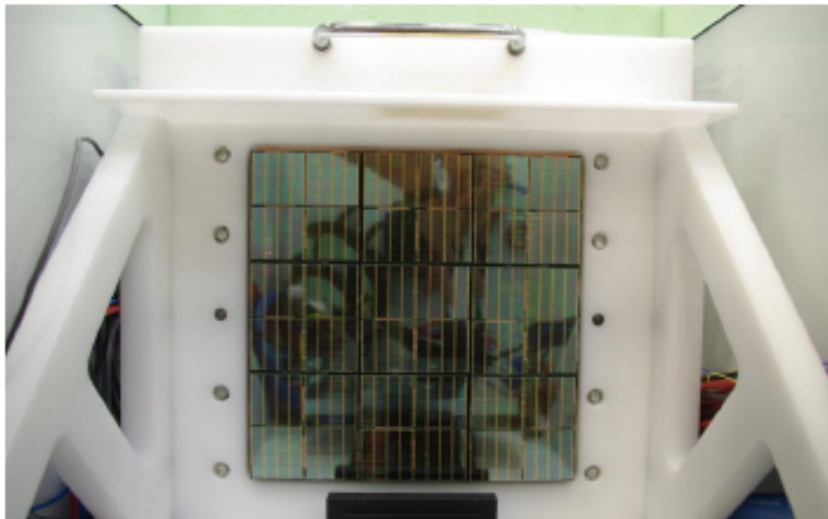


# FARICH prototype with DPC...



## 4-layer aerogel

- $n_{\max} = 1.046$
- Thickness 37.5 mm
- Calculated focal distance 200 mm
- Hermetic container with plexiglass window to avoid moisture condensation on aerogel



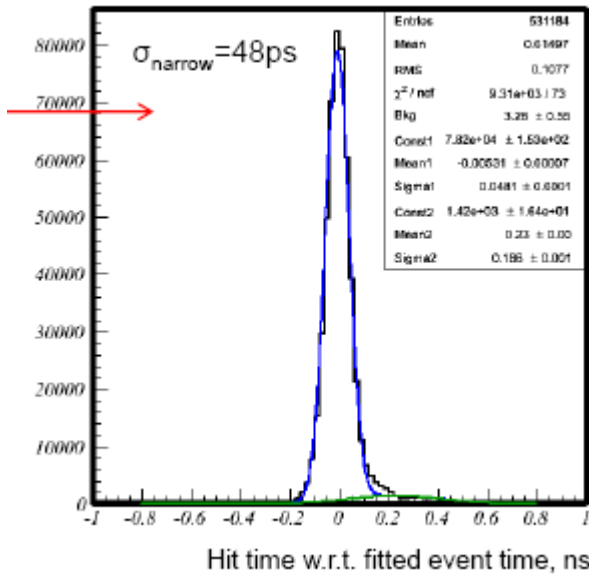
## Square matrix $20 \times 20 \text{ cm}^2$

- Sensors: DPC3200-22-44
- 3x3 modules = 6x6 tiles = 24x24 dies = 48x48 pixels in total
- 576 time channels
- 2304 amplitude (position) channels
- 4 levels of FPGA readout: tiles, modules, bus boards, test board

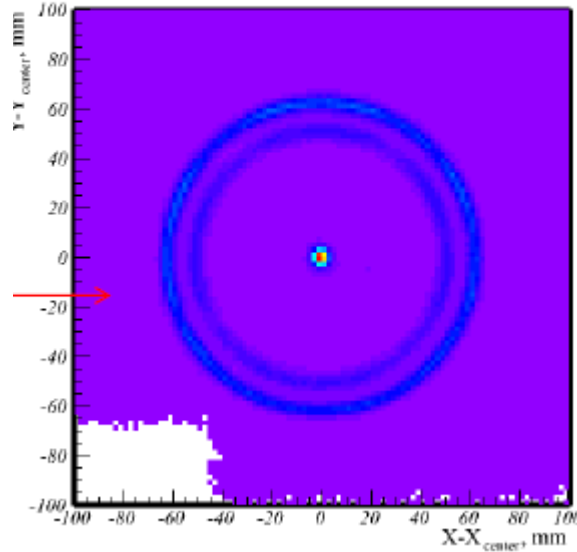


# Preliminary results from FARICH Detector Prototype @ CERN

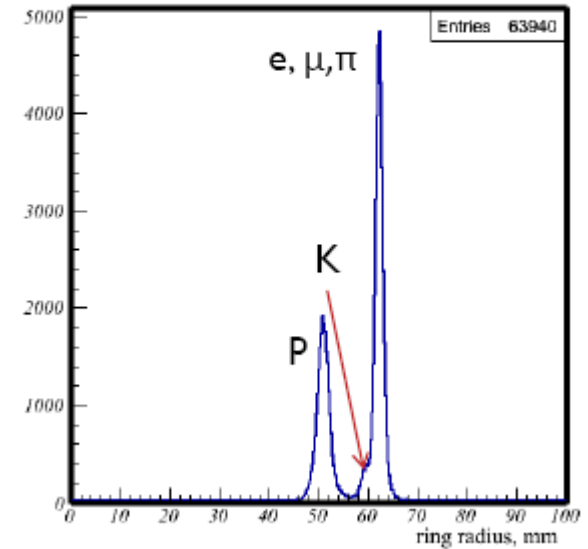
Intrinsic timing



Hit positions



Event distribution on radius

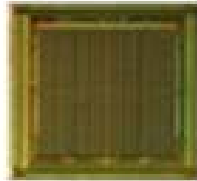


- Intrinsic timing resolution of full (20 x 20 cm<sup>2</sup>) detector:  $\sigma = 48 \text{ ps}$
- Discrimination of protons, kaons and pions with high angular resolution
- Curable damage of sensor at primary beam spot



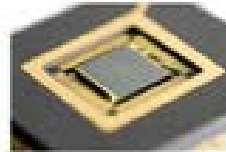
# Scalable Technology Maintains Intrinsic Performance

**DEMONSTRATOR:**  
single pixel



**CRT ~ 270 ps\***

**CHIP:**  
2 x 2 = 4 pixels



**CRT ~ 270 ps\***

**ARRAYS (TILES):**  
8 x 8 = 64 pixels



**CRT ~ 270 ps\***

**MODULES:**  
256 pixels



**CRT ~ 270 ps\***

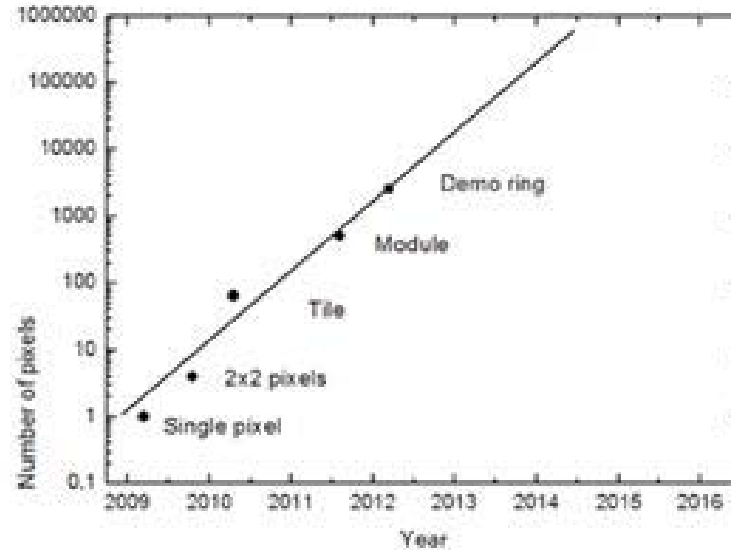
**DEMO RING:**  
2560 pixels



**CRT ~ 270 ps\***

**Many first time rights**

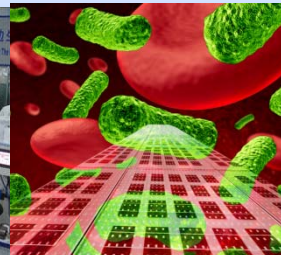
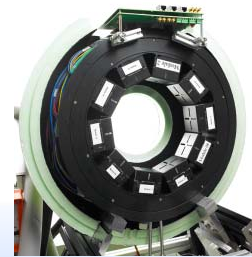
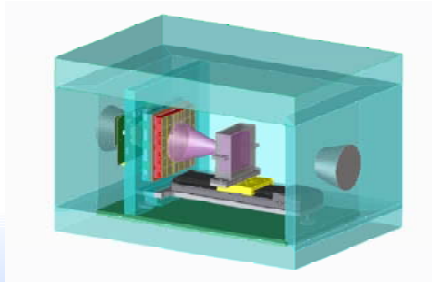
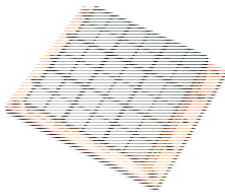
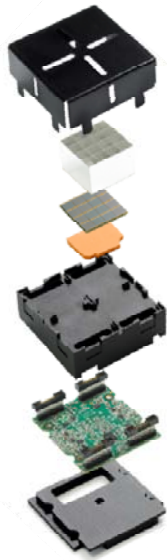
PDPC-Moore's law



\* Using 4x4x22 mm<sup>3</sup> LYSO crystals !!

# PDPC technology to business approach

Integration



**TEK 1 - POP  
(tile TEK)**

POP - proof of principle

**TEK 2 - POC  
(module TEK)**

POC - proof of concept

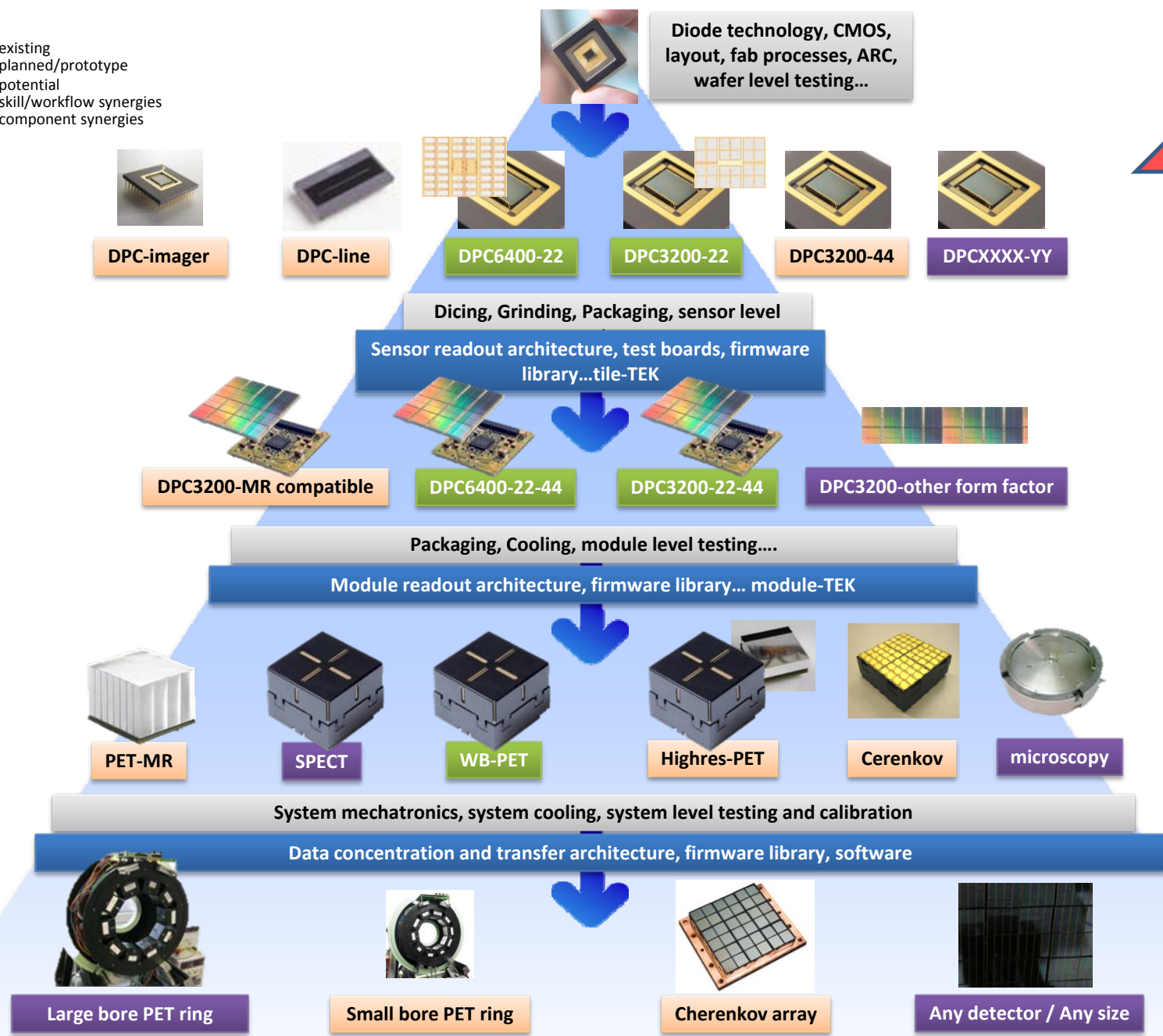
**Rapid  
prototyping**

**Application  
Business**



# The Philips tree of scalable DPC technology

- existing
- planned/prototype
- potential
- skill/workflow synergies
- component synergies

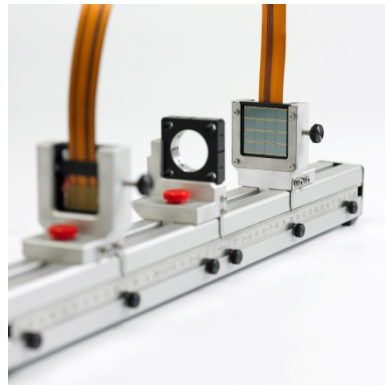


Costs of changes

- Technology Level
- Silicon Level
- Sensor Level
- Detector (module) Level
- Systems Level



# PDPC Technology Evaluation Kit (TEK)

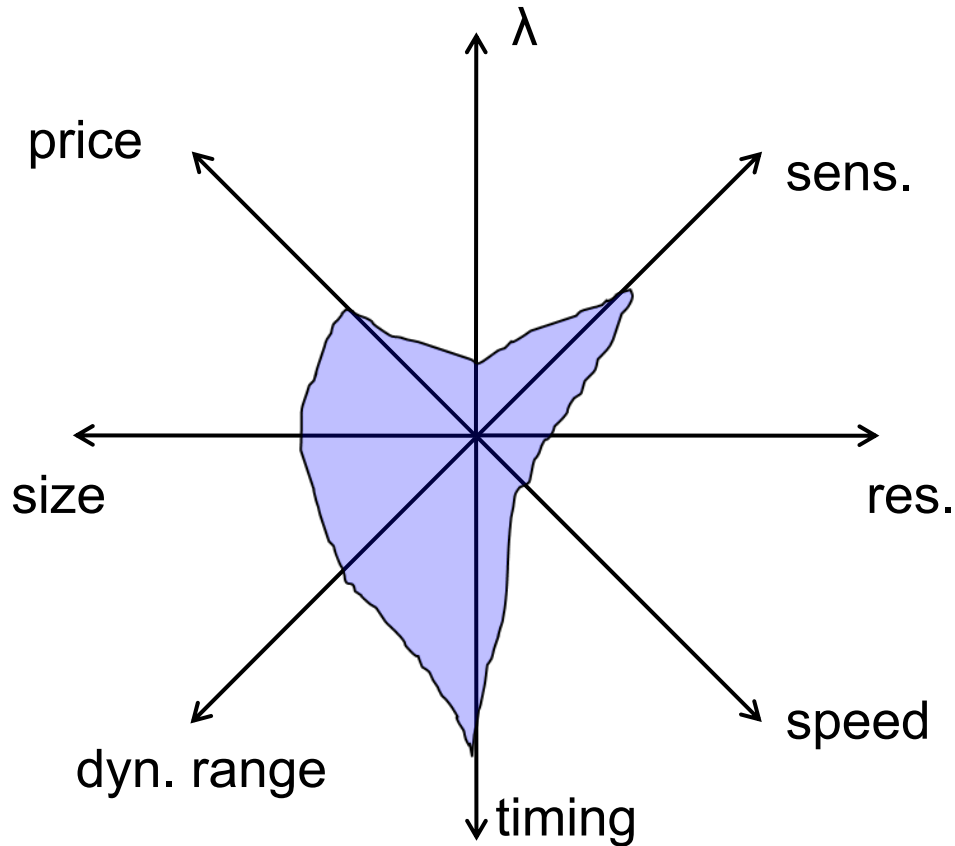


**> 30 kits installed so far**



## The future: what direction to go?

**DPC: current parameters are optimized for TOF-PET**





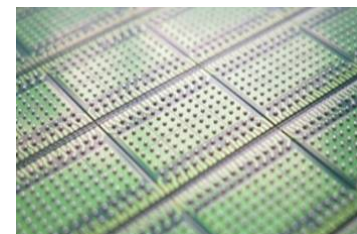
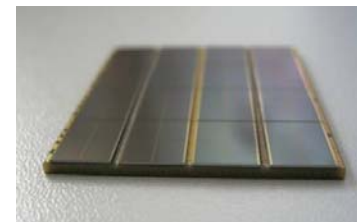
## Summary

- DPC is a **disruptive technology** that will induce changes in applications.
- DPC development was **triggered by ToF-PET** but can be expanded to other applications.
- DPC has shown **superior performance** and ease of use vs. analog SiPM technology (> 15 papers & posters @ IEEE2013).
- DPC demonstrated **scalability** of technology in maintaining intrinsic performance over larger systems:
  - *PDPC PET test ring*
  - *FARICH detector prototype*
- As a CMOS based technology DPC **needs volume** to succeed, therefore a systems architecture concept was developed.
- **New application areas** for DPC are explored by adapted designs.



## Outlook

- **Expansion of Scale** of technology:
  - *detectors with larger number of pixels*
  - *additional building blocks of scalable architecture*
- **Improved performance** of DPCs (2<sup>nd</sup> generation):
  - *higher PDE*
  - *less dead time*
  - *better intrinsic timing resolution*
  - *sub-pixel (2 mm<sup>2</sup>) readout*
  - *radiation hardness improvements*
- **New designs** for new applications
  - *line- and image sensors (FLIM, Spectroscopy)*
- **New technologies/materials** are under investigation
  - *TSV*
  - *WLP*
  - *ARC*
  - *3D technologies*
  - *Graphene and other 2D materials (further out)*



[http://www.youtube.com/watch?feature=player\\_embedded&v=dTSnhII1TsVg](http://www.youtube.com/watch?feature=player_embedded&v=dTSnhII1TsVg)

# Thank you very much for your attention!

Thanks also to:

**PET**

**FARICH**

**PDPC:**

Thomas Frach  
Mezbah Shaber  
Carsten Degenhardt  
Louis Meesen  
Ben Zwaans  
Oliver Muelhens  
Ralf Schulze  
Sebastian Reinartz  
Ralf Dorscheid  
Rik de Gruyter  
Anja Schmitz



**Philips Research:**

Andreia Trindade  
Pedro Rodrigues  
Andreas Thon  
Volkmar Schulz  
Torsten Solf  
Andre Salomon  
  
**FZ Juelich:**  
Siegfried Jahnke  
Gerhard Roeb  
Simone Beer  
Matthias Streun  
Marco Dautzenberg

**Budker Institute of  
Nuclear Physics, Novosibirsk**

A.Yu.Barnyakov  
M.Yu.Barnyakov  
V.S.Bobrovnikov  
A.R.Buzykaev  
V.V.Gulevich  
S.A.Kononov  
E.A.Kravchenko  
I.A.Kuyanov  
A.P.Onuchin  
I.V.Ovtin  
A.A.Talyshev

**Boreskov Institute,  
Novosibirsk**

*A.F. Danilyuk*

**Institute of Nuclear  
Research RAS, Moscow**

A.I.Berlev  
D.A.Finogeev  
T.L.Karavicheva  
E.V.Karpechev  
A.B.Kurepin  
A.N.Kurepin  
A.I.Maevskaya  
Yu.V.Musienko  
V.I.Razin  
A.I.Reshetin  
N.S.Topilskaya  
E.A.Usenko

[www.philips.com/digitalphotoncounting](http://www.philips.com/digitalphotoncounting)

[york.haemisch@philips.com](mailto:york.haemisch@philips.com)